

TYPES 2N1302, 2N1304, 2N1306, AND 2N1308 N-P-N ALLOY-JUNCTION GERMANIUM TRANSISTORS

electrical characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	2N1302			2N1304			2N1306			2N1308			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{CB0} Collector-Base Breakdown Voltage	$I_C = 100 \mu\text{a}$, $I_E = 0$	25	—	—	25	—	—	25	—	—	25	—	—	v
V_{EB0} Emitter-Base Breakdown Voltage	$I_E = 100 \mu\text{a}$, $I_C = 0$	25	—	—	25	—	—	25	—	—	25	—	—	v
$^*V_{PT}$ Punch Through Voltage†	$V_{EB1} = 1 \text{ v}$	25	—	—	20	—	—	15	—	—	15	—	—	v
$^*I_{CB0}$ Collector Cutoff Current	$V_{CB} = 25 \text{ v}$, $I_E = 0$	—	3	6	—	3	6	—	3	6	—	3	6	μa
$^*I_{EB0}$ Emitter Cutoff Current	$V_{EB} = 25 \text{ v}$, $I_C = 0$	—	2	6	—	2	6	—	2	6	—	2	6	μa
$^*h_{FE}$ Static Forward Current Transfer Ratio	$V_{CE} = 1 \text{ v}$, $I_C = 10 \text{ ma}$	20	100	—	40	115	200	60	130	300	80	160	—	—
	$V_{CE} = 0.35 \text{ v}$, $I_C = 200 \text{ ma}$	10	100	—	15	110	—	20	125	—	20	140	—	—
$^*V_{CE(sat)}$ Collector-Emitter Saturation Voltage	$I_B = 0.5 \text{ ma}$, $I_C = 10 \text{ ma}$	0.15	0.22	0.40	0.15	0.22	0.35	0.15	0.22	0.35	0.15	0.22	0.35	v
	$I_B = 0.5 \text{ ma}$, $I_C = 10 \text{ ma}$	—	0.07	0.20	—	—	—	—	—	—	—	—	—	v
	$I_B = 0.25 \text{ ma}$, $I_C = 10 \text{ ma}$	—	—	—	—	0.07	0.20	—	—	—	—	—	—	v
	$I_B = 0.17 \text{ ma}$, $I_C = 10 \text{ ma}$	—	—	—	—	—	—	—	0.07	0.20	—	—	—	v
h_{ib} Small-Signal Common-Base Input Impedance	$V_{CB} = 5 \text{ v}$, $I_E = -1 \text{ ma}$ $f = 1 \text{ kc}$	—	20	—	—	20	—	—	20	—	—	20	—	ohm
h_{rb} Small-Signal Common-Base Reverse Voltage Transfer Ratio	$V_{CB} = 5 \text{ v}$, $I_E = -1 \text{ ma}$ $f = 1 \text{ kc}$	—	5×10^{-4}	—	—	5×10^{-4}	—	—	5×10^{-4}	—	—	5×10^{-4}	—	—
h_{ob} Small-Signal Common-Base Output Admittance	$V_{CB} = 5 \text{ v}$, $I_E = -1 \text{ ma}$ $f = 1 \text{ kc}$	—	0.34	—	—	0.34	—	—	0.34	—	—	0.34	—	μmho
h_{fe} Small-Signal Common-Emitter Forward Current Transfer Ratio	$V_{CE} = 5 \text{ v}$, $I_C = 1 \text{ ma}$ $f = 1 \text{ kc}$	—	105	—	—	120	—	—	135	—	—	170	—	—
$^*f_{Tb}$ Common-Base Alpha-Cutoff Frequency	$V_{CB} = 5 \text{ v}$, $I_E = -1 \text{ ma}$	3	12	—	5	14	—	10	16	—	15	20	—	mc
C_{ob} Common-Base Open Circuit Output Capacitance	$V_{CB} = 5 \text{ v}$, $I_E = 0$ $f = 1 \text{ mc}$	—	14	20	—	14	20	—	14	20	—	14	20	pf
C_{ib} Common-Base Open-Circuit Input Capacitance	$V_{EB} = 5 \text{ v}$, $I_C = 0$ $f = 1 \text{ mc}$	—	13	—	—	13	—	—	13	—	—	13	—	pf

† V_{PT} is determined by measuring the emitter-base floating potential V_{EB1} . The collector-base voltage, V_{CB} , is increased until $V_{EB1} = 1$ volt; this value of $V_{CB} = (V_{PT} + 1 \text{ v})$.

switching characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS††	2N1302			2N1304			2N1306			2N1308			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_d Delay Time	$I_C = 10 \text{ ma}$, $I_{B(1)} = 1.3 \text{ ma}$ $I_{B(2)} = -0.7 \text{ ma}$, $V_{BE(orf)} = -0.8 \text{ v}$ $R_L = 1 \text{ k } \Omega$ (See Fig. 1)	—	0.07	—	—	0.07	—	—	0.06	—	—	0.06	—	μsec
t_r Rise Time		—	0.20	—	—	0.20	—	—	0.18	—	—	0.15	—	μsec
t_s Storage Time		—	0.70	—	—	0.70	—	—	0.64	—	—	0.64	—	μsec
t_f Fall Time		—	0.40	—	—	0.40	—	—	0.36	—	—	0.34	—	μsec
Q_{sb} Stored Base Charge	$I_{B(1)} = 1 \text{ ma}$, $I_C = 10 \text{ ma}$ (See Fig. 2)	—	800	—	—	760	—	—	720	—	—	680	—	pcb

††Voltage and current values shown are nominal; exact values vary slightly with device parameters.

operating characteristics at 25°C free-air temperature

PARAMETER	TEST CONDITIONS	2N1302			2N1304			2N1306			2N1308			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
NF Spot Noise Figure	$V_{CB} = 5 \text{ v}$ $I_B = -1 \text{ ma}$ $f = 1 \text{ kc}$, $R_o = 1 \text{ k } \Omega$	—	4	—	—	4	—	—	3	—	—	3	—	db